

# 2SK2220, 2SK2221

Silicon N-Channel MOS FET

# HITACHI

ADE-208-1352 (Z)

1st. Edition

Mar. 2001

## Application

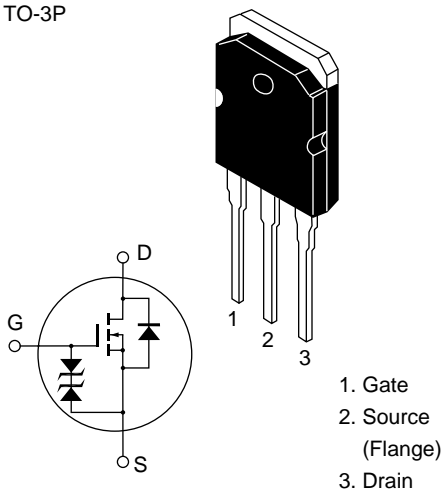
Low frequency power amplifier  
Complementary pair with 2SJ351, 2SJ352

## Features

- High power gain
- Excellent frequency response
- High speed switching
- Wide area of safe operation
- Enhancement-mode
- Good complementary characteristics
- Equipped with gate protection diodes

## Outline

TO-3P



## 2SK2220, 2SK2221

### Absolute Maximum Ratings (Ta = 25°C)

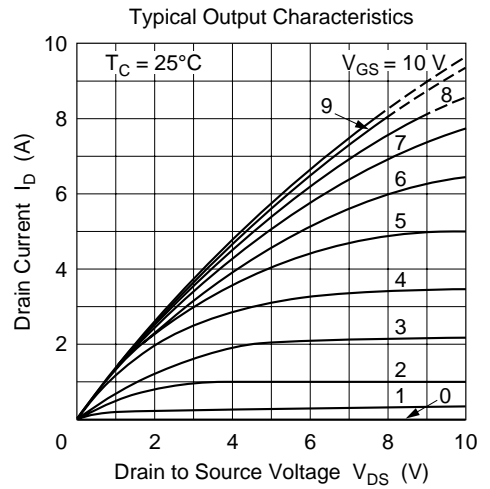
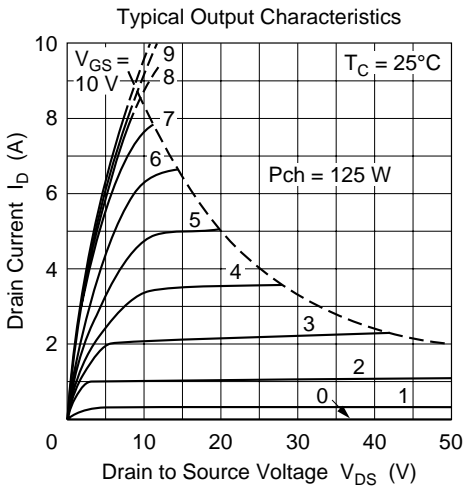
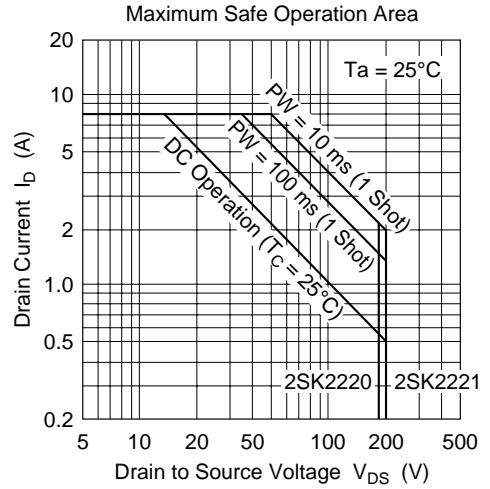
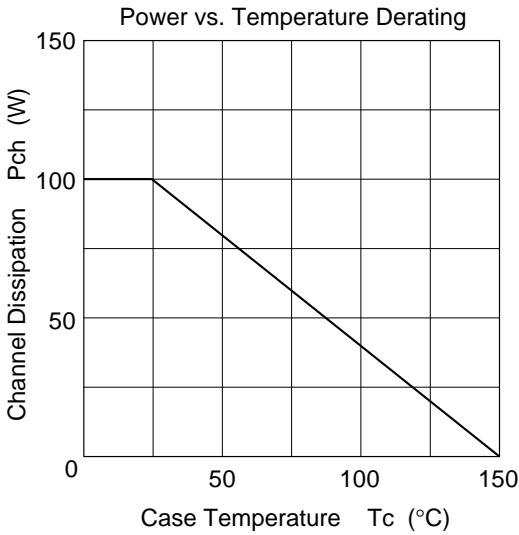
Item		Symbol	Ratings	Unit
Drain to source voltage	2SK2220	$V_{DSX}$	180	V
	2SK2221		200	
Gate to source voltage		$V_{GSS}$	±20	V
Drain current		$I_D$	8	A
Body to drain diode reverse drain current		$I_{DR}$	8	A
Channel dissipation		$P_{ch}^{*1}$	100	W
Channel temperature		$T_{ch}$	150	°C
Storage temperature		$T_{stg}$	-55 to +150	°C

Note 1. Value at Tc = 25 °C

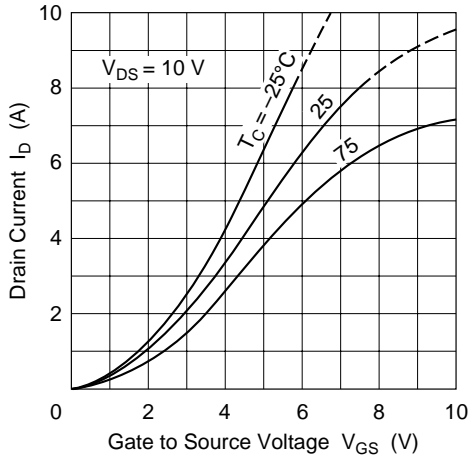
### Electrical Characteristics (Ta = 25°C)

Item		Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	2SK2220	$V_{(BR)DSX}$	180	—	—	V	$I_D = 10 \text{ mA}$ , $V_{GS} = -10 \text{ V}$
	2SK2221		200	—	—		
Gate to source breakdown voltage		$V_{(BR)GSS}$	±20	—	—	V	$I_G = \pm 100 \mu\text{A}$ , $V_{DS} = 0$
Gate to source cutoff voltage		$V_{GS(off)}$	0.15	—	1.45	V	$I_D = 100 \text{ mA}$ $V_{DS} = 10 \text{ V}$
Drain to source saturation voltage		$V_{DS(sat)}$	—	—	12	V	$I_D = 8 \text{ A}$ , $V_{GD} = 0 \text{ V}^{*1}$
Forward transfer admittance		$ y_{fs} $	0.7	1.0	1.4	S	$I_D = 3 \text{ A}$ $V_{DS} = 10 \text{ V}^{*1}$
Input capacitance		$C_{iss}$	—	600	—	pF	$V_{GS} = -5 \text{ V}$
Output capacitance		$C_{oss}$	—	800	—	pF	$V_{DS} = 10 \text{ V}$
Reverse transfer capacitance		$C_{rss}$	—	8	—	pF	$f = 1 \text{ MHz}$
Turn-on time		$t_{on}$	—	250	—	ns	$V_{DD} = 30 \text{ V}$
Turn-off time		$t_{off}$	—	90	—	ns	$I_D = 4 \text{ A}$

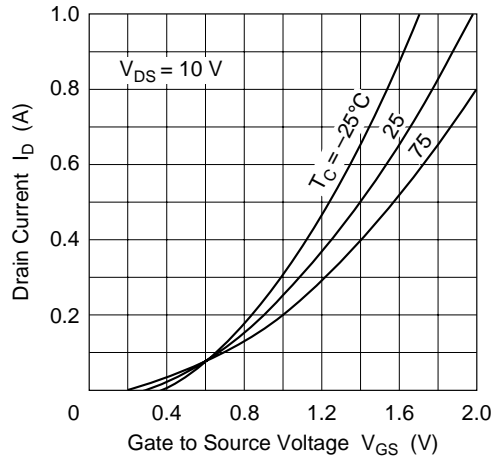
Note 1. Pulse Test



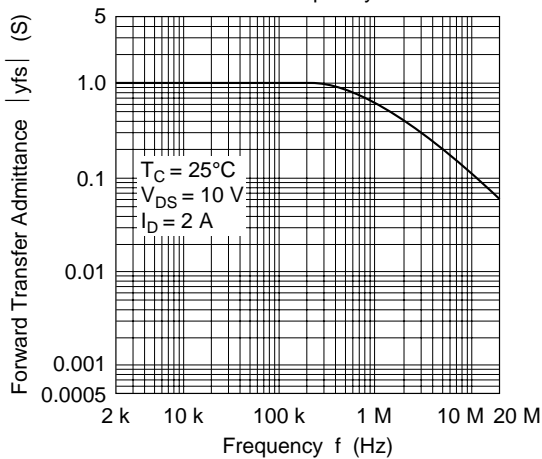
Typical Transfer Characteristics



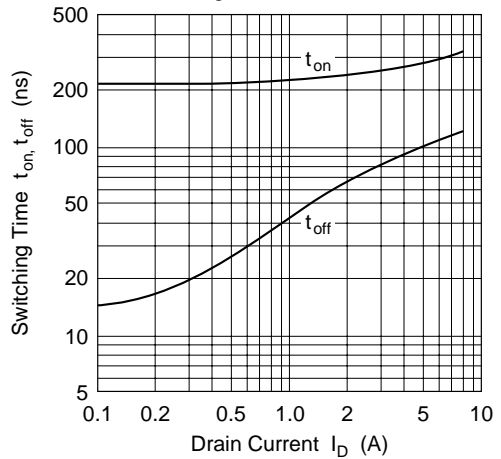
Typical Transfer Characteristics



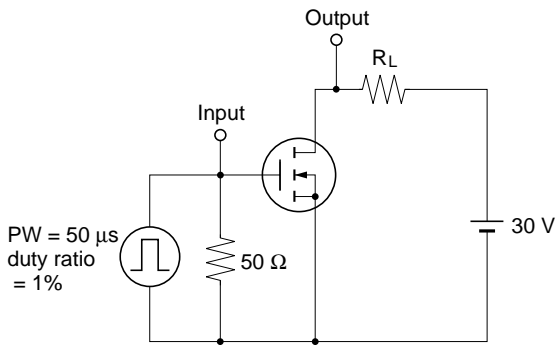
Forward Transfer Admittance vs. Frequency



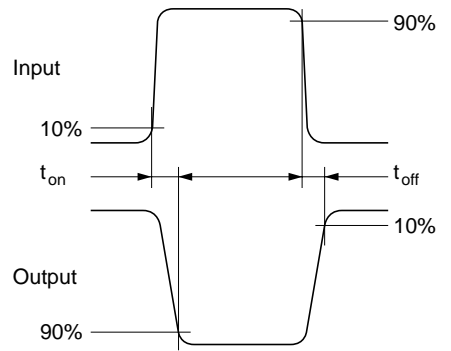
Switching Time vs. Drain Current



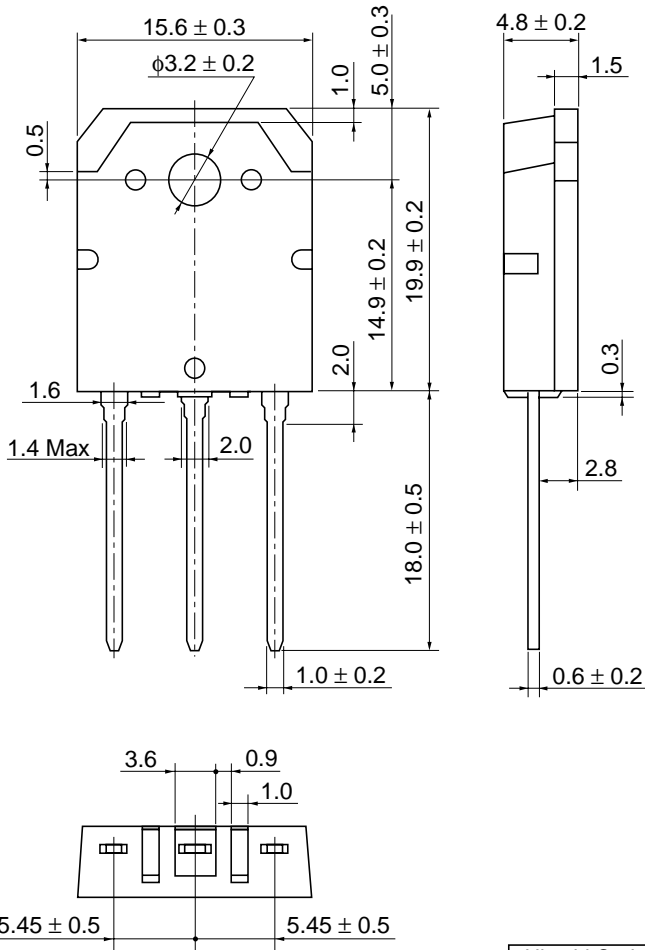
Switching Time Test Circuit



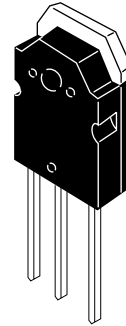
Waveforms



Package Dimensions



As of January, 2001  
Unit: mm



Hitachi Code	TO-3P
JEDEC	—
EIAJ	Conforms
Mass (reference value)	5.0 g

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